## Bihar Engineering University, Patna End Semester Examination - 2022

Semester: 111

Course: B.Tech. Code: 100302

Subject: Analogy Electronics Circuits

Time: 03 Hours Full Marks: 70

[7]

	ruction	-0-				
(i)	The marks are indicated in the right-hand margin.					
ii)	There	There are NINE questions in this paper.				
iii)	Attem	Attempt FIVE questions in all.				
iv)	Quest	Question No. 1 is compulsory.				
Q. 1	Cho	Choose the correct answer of the following (Any seven question only): $[2 \times 7 = 14]$ (a) For a base current of $10\mu$ A, what is the value of collector current in common emitter if				
	(a)	For a base current of $10\mu A$ , what is the $\beta_{dc}$ = 100?	value of collector current in common carre			
		(i) 10 μA	(ii) 100 μA			
		(iii) lmA	(iv) 10mA	200/		
	(b) If an amplifier with gain of -1000 and feedback factor β= -0.1 had a gain of the temperature, the change in gain of the feedback amplifier would be					
		(i) 10%	(ii) 5%			
		(iii) 0.2%	(iv) 0.01%			
	(c)	A trivalent impurity has Valer	nce electrons.			
		(i) 4	(ii) 5			
		(iii) 6	(iv) 3			
	(d)	Zener diodes are used primarily as	****			
		(i) Amplifiers	(ii) Voltage regulators			
		(iii) Rectifiers	(iv) Oscillators			
	(e) Peak inverse voltage of diode used in Half-wave rectifier is					
		(i) 2Vm	(ii) Vm/2			
		(iii) Vm	(iv) Vm/3			
	(f)	For every 10°C increase in temperature, will be increased by:	the reverse saturation current of a p-n june	tion		
		(i) 10 times	(ii) 2 times			
		(iii) 4 times	(iv) Remain same			
	(g)	ion when the base-emitter junction is forw reverse-biased?	ard-			
		(i) Active region	(ii) Saturation region			
		(iii) Cutoff region	(iv) Reverse active region			
	(h) In an RC phase shift oscillator, the phase shift provided by each RC stage is:					
		(i) 30 degree	(ii) 45 degree			
		(iii) 60 degree	(iv) 90 degree			
	(i)	If the PIV rating of a diode is exceeded	2.00			
	. ,	(i) the diode conducts poorly	(ii) the diode is destroyed			
		(iii) the diode behaves as Zener diode	(iv) None of the above			
	(j)	(j) For $I_{DDS} = 9$ mA and $V_p = -3.5$ V, $I_D$ for $V_{GS} = 0$ V is				
		(i) 8 mA	(ii) 9 mA			
		(iii) 10 mA	(iv) 11 mA			
		100/10/10/3	··· A II MA			

Define the following:

Common mode rejection ratio (CMRR)

Gain bandwidth product

Slew rate of op-amp

Q.2 (a)

(i)

(ii) (iii)

	aria system to oscillate with feedback.	[7]
(b)	State the Barkhausen condition for an electronic system	
	Derive the expression for stability factor for fix bias circuit with respect to ICO VBE	[7]
(a) (b)	and p. $R = 3.3k\Omega$ . $R = 1.82$ and	[7]
	CC=18V. The silicon transistor has used p factor.	
	to concept of feedback.	[7]
(a)	With the help of block diagram, explain the concept of the purpose of providing –	[17]
(b)	Discuss with the help of circuit example, the purpose	
	and the state of the same of t	
(a)	With a neat circuit diagram and waveforms, explain the working of full wave bridge	[7]
	rectifier and show that its ripple factor is 0.48.	[7]
(b)	Describe in detail the avalanche and Zener breakdown income	
	Desires the expression for output voltage of an instrumentation amplifier. Also write	[8]
(a)	to a december and disadvantages	161
(b)	For an N-channel MOSFET the parameters given as $\mu C_{ox} \frac{w}{L} = \frac{0.2MA}{V^2}$ , $V_{DS} = 0.2V$ ,	[6]
(-)	and $V_t = 0.7V$ . Find the region of operation and the drain current.	
(-)	Differentiate between JFET and BJT indicating the advantages and disadvantages.	[7]
	What is faithful amplification? Explain the conditions to be further to defice	[7]
(0)	faithful amplification in transistor amplifier.	
(a)	Draw and explain the pin configuration of a 741 Op-Amp. Also explain the internal	[7]
(b)		[7]
0 (0)	State the characteristics of an ideal transformer.	[2]
	Define rms value, form factor, peak factor, complex power and han power	[5]
(c	Two two-port network a and b, with open-circuit impedances Z <sub>a</sub> and Z <sub>b</sub> are connected in series. Drive the Z-parameter equations.	[7]
	(a) (b) (a) (b) (a) (b) (a) (b) (a) (b) (b) (b)	<ul> <li>(a) Derive the expression for stability factor for fix bias circuit with respect to I<sub>CO</sub>. V<sub>BE</sub> and β.</li> <li>(b) A voltage divider biased circuit has R<sub>1</sub>=39kΩ. R<sub>2</sub>=82kΩ. R<sub>C</sub>=3.3kΩ. R<sub>E</sub>=1kΩ and CC=18V. The silicon transistor has used β = 120. Find Q - point and stability factor.</li> <li>(a) With the help of block diagram, explain the concept of feedback.</li> <li>(b) Discuss with the help of circuit example, the purpose of providing - (i) negative feedback;</li> <li>(ii) positive feedback in amplifier.</li> <li>(a) With a neat circuit diagram and waveforms, explain the working of full wave bridge rectifier and show that its ripple factor is 0.48.</li> <li>(b) Describe in detail the avalanche and Zener breakdown mechanism in Zener diode.</li> <li>(a) Derive the expression for output voltage of an instrumentation amplifier. Also write its advantages and disadvantages</li> <li>(b) For an N-channel MOSFET the parameters given as μC<sub>OX</sub> w/L = 0.2MA, V<sub>DS</sub> = 0.2V, and V<sub>I</sub> = 0.7V. Find the region of operation and the drain current.</li> <li>(a) Differentiate between JFET and BJT indicating the advantages and disadvantages. What is faithful amplification? Explain the conditions to be fulfilled to achieve faithful amplification in transistor amplifier.</li> <li>(a) Draw and explain the pin configuration of a 741 Op-Amp. Also explain the internal structure of an Op-Amp with the help of block diagram.</li> <li>(b) For the circuit shown below. Assume zener voltage to be 4.78v and voltage drop across the forward biased zener to be 0.7v. Find the peak voltage of output.</li> <li>9 (a) State the characteristics of an ideal transformer.</li> <li>(b) Define rms value, form factor, peak factor, complex power and half power frequency.</li> <li>(c) The two-post network a and b, with open-circuit impedances Z<sub>a</sub> and Z<sub>b</sub> are</li> </ul>

